

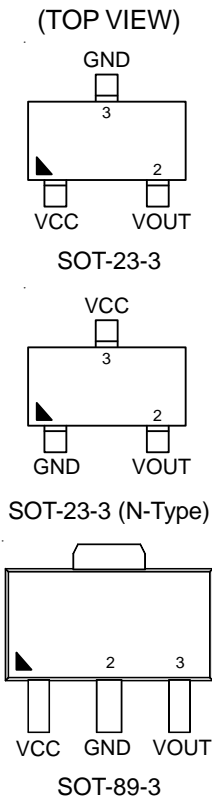
1 μ A I_Q, 250mA Low-Dropout Linear Regulator

General Description

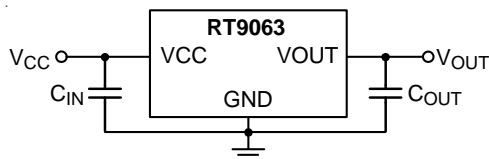
The RT9063 is a low-dropout (LDO) linear regulator that features high input voltage, low dropout voltage, ultra-low operating current, and miniaturized packaging. With quiescent current as low as 1 μ A, the RT9063 is ideal for battery-powered equipment.

The RT9063's stability requirements are easily met with all types of output capacitors, including tiny ceramic capacitors, over its wide input range and its load current range (0mA to 250mA). The RT9063 offers standard output voltages of 1.2V, 1.5V, 1.8V, 2.5V and 3.3V.

Pin Configurations



Simplified Application Circuit



Features

- 1 μ A Quiescent Current
- \pm 2% Output Accuracy
- 250mA Output Current
- Dropout Voltage : 0.4V at 200mA
- Fixed Output Voltage 1.2V/1.5V/1.8V/2.5V/3.3V
- Stable with Ceramic or Tantalum Capacitor
- Current Limit Protection
- Over-Temperature Protection
- SOT-23-3, SOT-89-3 Packages
- RoHS Compliant and Halogen Free

Applications

- Portable, Battery Powered Equipment
- Ultra Low Power Microcontrollers

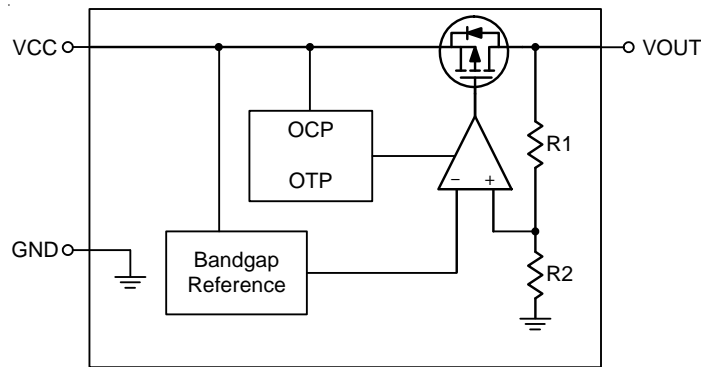
Ordering and Marking Information

Part Number	Output Voltage	Package	Marking Information
RT9063-12GV	1.2V	SOT-23-3	0G=
RT9063-12GVN		SOT-23-3 (N)	2T=
RT9063-12GX		SOT-89-3	07=
RT9063-15GV	1.5V	SOT-23-3	2M=
RT9063-15GVN		SOT-23-3 (N)	2U=
RT9063-18GV		1.8V	SOT-23-3
RT9063-18GVN	SOT-23-3 (N)		2V=
RT9063-18GX	SOT-89-3		08=
RT9063-23GV	2.3V	SOT-23-3	47=
RT9063-23GVN		SOT-23-3 (N)	42=
RT9063-25GV	2.5V	SOT-23-3	0J=
RT9063-25GVN		SOT-23-3 (N)	2W=
RT9063-25GX		SOT-89-3	09=
RT9063-27GV	2.7V	SOT-23-3	48=
RT9063-27GVN		SOT-23-3 (N)	43=
RT9063-28GV	2.8V	SOT-23-3	49=
RT9063-28GVN		SOT-23-3 (N)	44=
RT9063-33GV	3.3V	SOT-23-3	0K=
RT9063-33GVN		SOT-23-3 (N)	2X=
RT9063-33GX		SOT-89-3	0A=

Functional Pin Description

Pin No.			Pin Name	Pin Function
SOT-23-3	SOT-23-3 (N-Type)	SOT-89-3		
1	3	1	VCC	Supply Voltage Input.
2	2	3	VOUT	Output of the Regulator.
3	1	2	GND	Ground.

Function Block Diagram



Operation

The RT9063 is a high input voltage linear regulator specifically designed to minimize external components.

The minimum required output capacitance for stable operation is 1μF effective capacitance after consideration of the temperature and voltage coefficient of the capacitor.

Output Transistor

The RT9063 includes a built-in low on-resistance P-MOSFET output transistor for low dropout voltage applications.

Error Amplifier

The Error Amplifier compares the output feedback voltage from an internal feedback voltage divider to an internal reference voltage and controls the P-MOSFET's gate voltage to maintain output voltage regulation.

Current Limit

The RT9063 provides a current limit function to prevent damage during output over-load or shorted-circuit conditions. The output current is detected by an internal sensing transistor.

Over-Temperature Protection

The over-temperature protection function will turn off the P-MOSFET when the internal junction temperature exceeds 150°C (typ.) and the output current exceeds 30mA. Once the junction temperature cools down by approximately 20°C, the regulator will automatically resume operation.

Absolute Maximum Ratings (Note 1)

- VCC to GND ----- -0.3V to 7V
- VOUT to VCC ----- -7V to 0.3V
- VOUT to GND ----- -0.3V to 7V
- Power Dissipation, P_D @ T_A = 25°C
 - SOT-23-3 ----- 0.41W
 - SOT-89-3 ----- 0.59W
- Package Thermal Resistance (Note 2)
 - SOT-23-3, θ_{JA} ----- 243.3°C/W
 - SOT-89-3, θ_{JA} ----- 167.7°C/W
- Lead Temperature (Soldering, 10 sec.) ----- 260°C
- Junction Temperature ----- 150°C
- Storage Temperature Range ----- -65°C to 150°C
- ESD Susceptibility (Note 3)
 - HBM (Human Body Model) ----- 2kV
 - MM (Machine Model) ----- 200V

Recommended Operating Conditions (Note 4)

- Supply Input Voltage, VCC ----- 2.5V to 6V
- Junction Temperature Range ----- -40°C to 125°C
- Ambient Temperature Range ----- -40°C to 85°C

Electrical Characteristics

((V_{OUT} + 1) < V_{CC} < 6V, T_A = 25°C, unless otherwise specified.)

Parameter	Symbol	Test Conditions	Min	Typ	Max	Unit
Output Voltage Range	V _{OUT}		1.2	--	3.3	V
DC Output Accuracy		I _{LOAD} = 1mA	-2	--	2	%
Dropout Voltage	V _{Drop}	I _{LOAD} = 0.2A, V _{OUT} ≥ 3V	--	0.4	1.2	V
		I _{LOAD} = 0.1A, V _{OUT} < 3V	--	0.3	1	
Quiescent Current	I _Q	No Load	--	1	3	μA
Line Regulation		I _{LOAD} = 1mA, V _{OUT} > 1.8V	--	0.6	1	%
		I _{LOAD} = 1mA, V _{OUT} ≤ 1.8V	--	0.6	1.3	
Load Regulation		10mA < I _{LOAD} < 200mA, V _{OUT} < 1.5V	--	1	1.4	%
		10mA < I _{LOAD} < 200mA, 1.5V ≤ V _{OUT} < 2.5V	--	0.7	1.2	
		10mA < I _{LOAD} < 250mA, V _{OUT} ≥ 2.5V	--	0.6	1	
Power Supply Rejection Ratio	PSRR	f = 100Hz, I _{OUT} = 50mA	--	-70	--	dB
		f = 10kHz, I _{OUT} = 50mA	--	-40	--	
Output Current Limit		V _{OUT} = 0.5 x V _{OUT(Normal)}	300	400	500	mA
OTP Threshold			--	150	--	°C
OTP Hysteresis			--	20	--	°C

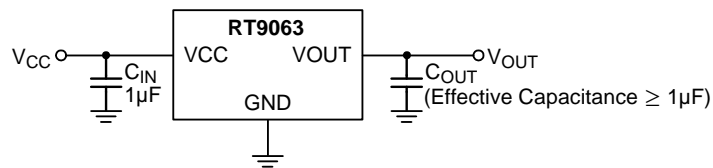
Note 1. Stresses beyond those listed “Absolute Maximum Ratings” may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions may affect device reliability.

Note 2. θ_{JA} is measured at $T_A = 25^\circ\text{C}$ on a high effective thermal conductivity four-layer test board per JEDEC 51-7.

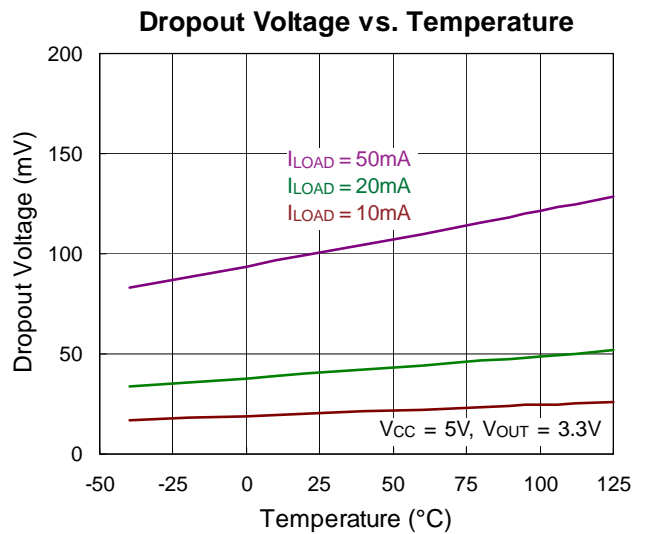
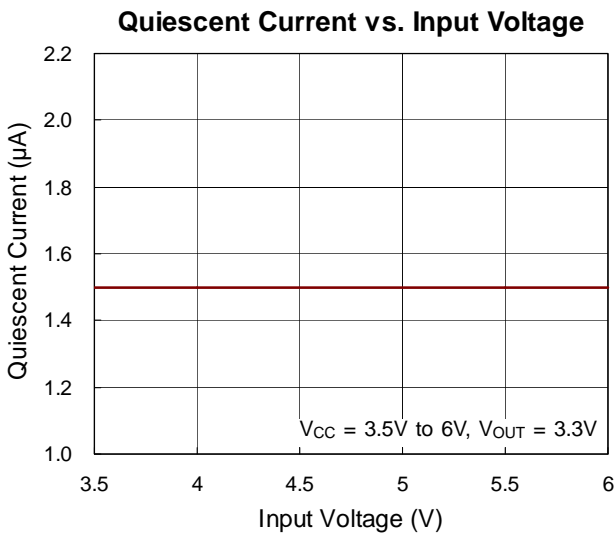
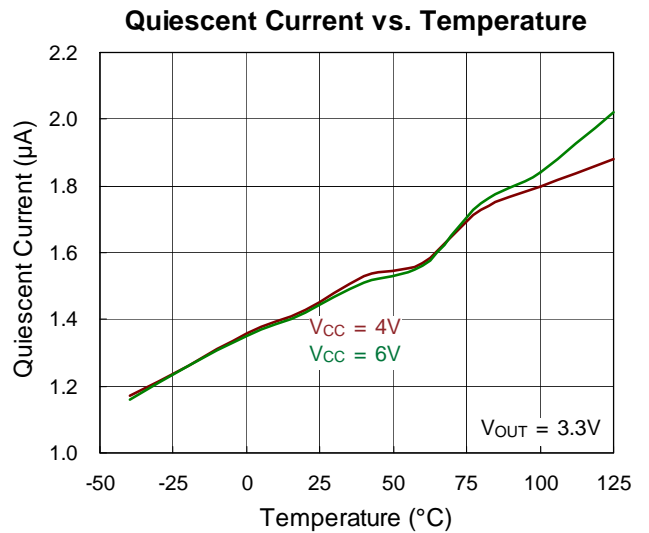
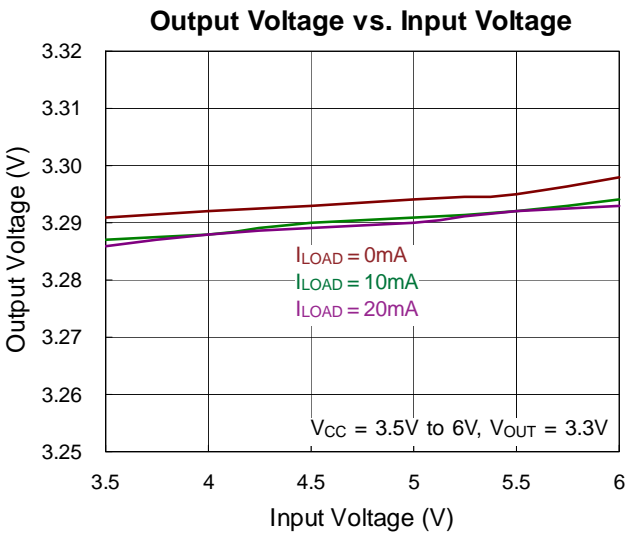
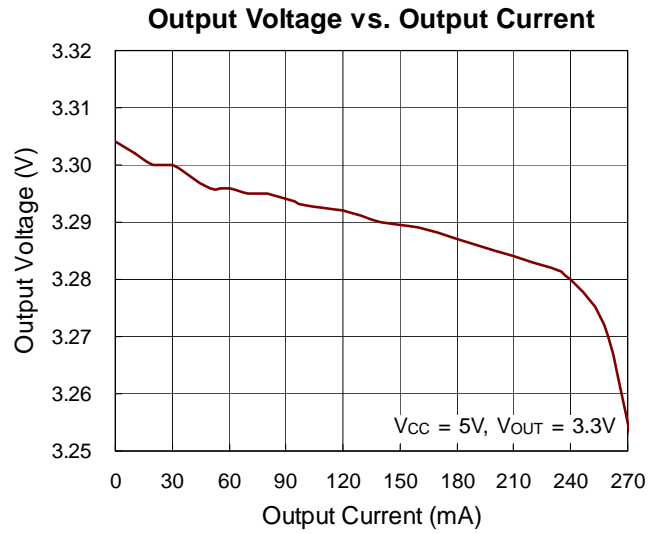
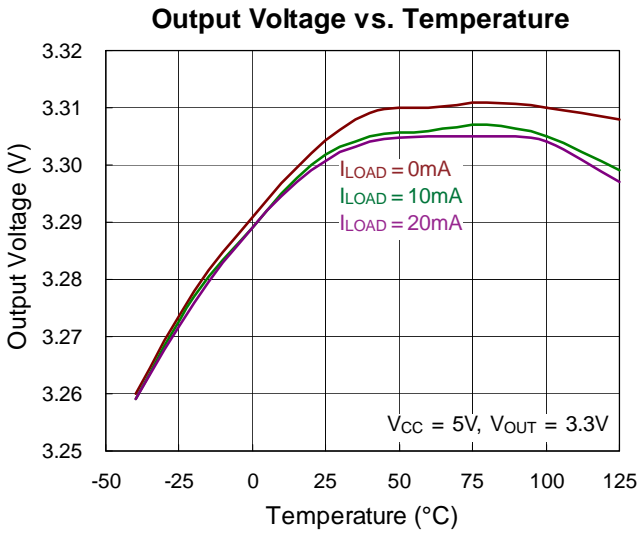
Note 3. Devices are ESD sensitive. Handling precaution is recommended.

Note 4. The device is not guaranteed to function outside its operating conditions.

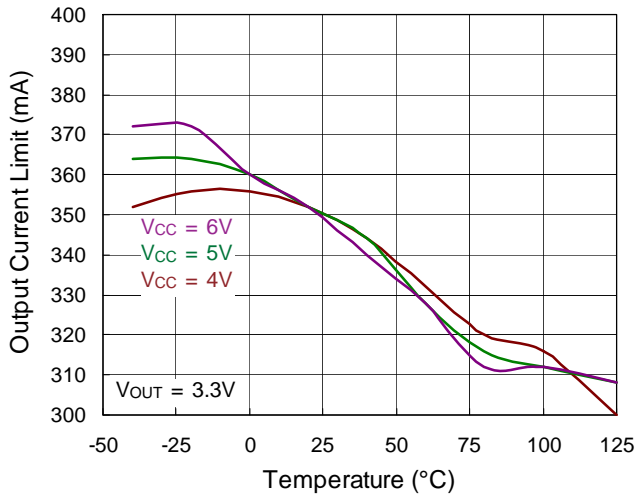
Typical Application Circuit



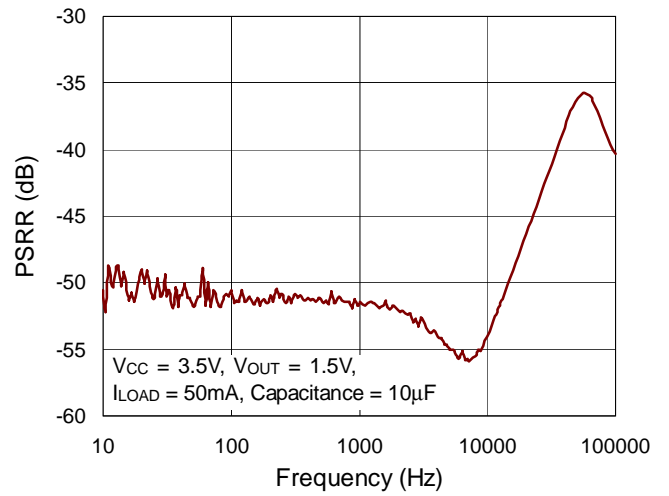
Typical Operating Characteristics



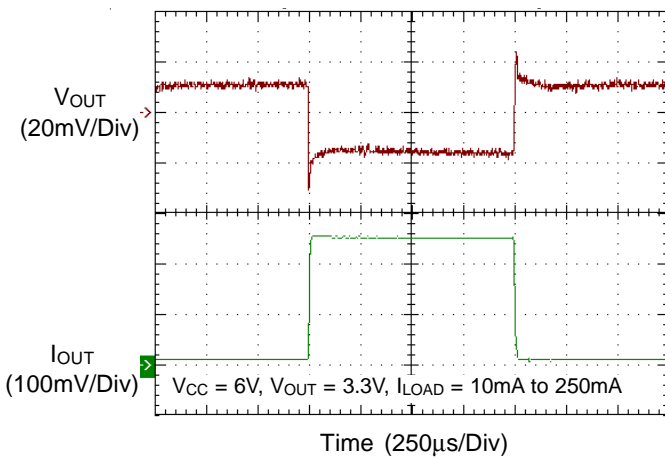
Output Current Limit vs. Temperature



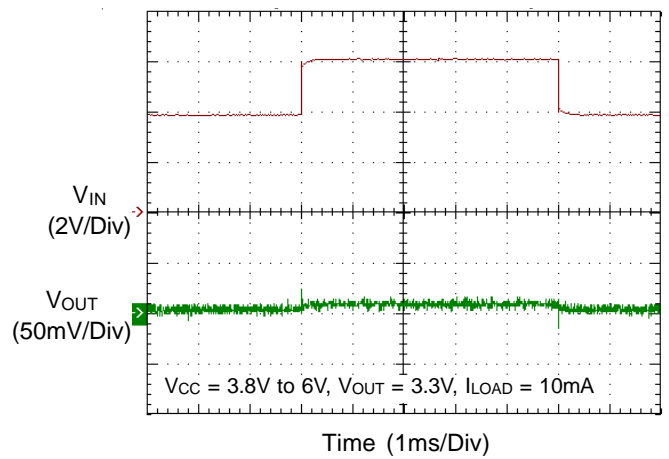
Power Supply Rejection Ratio



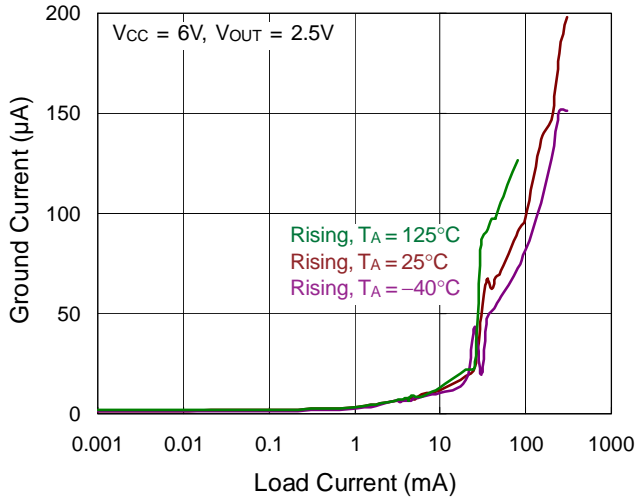
Load Transient Response



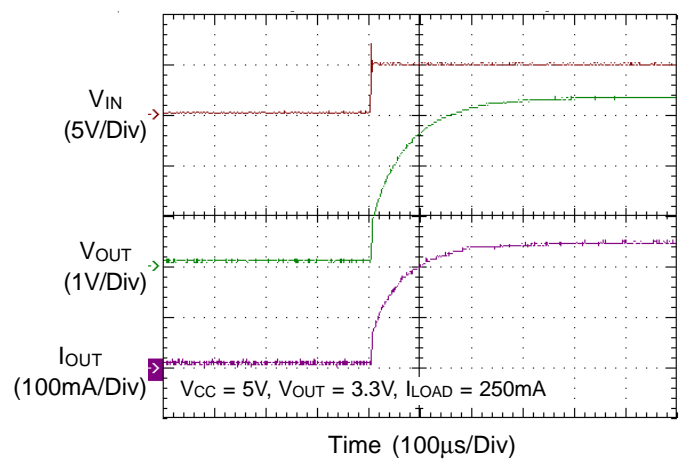
Line Transient Response



Ground Current vs. Load Current



Power Up Response



Applications Information

Like any low dropout linear regulator, the RT9063's external input and output capacitors must be properly selected for stability and performance. Use a 1µF or larger input capacitor and place it close to the IC's VCC and GND pins.

Any output capacitor meeting the minimum 1mΩ ESR (Equivalent Series Resistance) and effective capacitance larger than 1µF requirement may be used. Place the output capacitor close to the IC's VOUT and GND pins. Increasing capacitance and decreasing ESR can improve the circuit's PSRR and line transient response.

Thermal Considerations

For continuous operation, do not exceed absolute the maximum junction temperature. The maximum power dissipation depends on the thermal resistance of the IC package, PCB layout, rate of surrounding airflow, and the allowed difference between the junction and ambient temperatures. The maximum power dissipation can be calculated by the following formula :

$$P_{D(MAX)} = (T_{J(MAX)} - T_A) / \theta_{JA}$$

where $T_{J(MAX)}$ is the maximum junction temperature, T_A is the ambient temperature, and θ_{JA} is the junction to ambient thermal resistance.

The recommended operating conditions specify a maximum junction temperature is 125°C. The junction to ambient thermal resistance, θ_{JA} , is layout dependent. On a standard JEDEC 51-7 four-layer thermal test board , the thermal resistance, θ_{JA} , of the SOT-23-3 package is 243.3°C/W. For the SOT-89-3 package, the θ_{JA} , is 167.7°C/W. The maximum power dissipation at $T_A = 25^\circ\text{C}$ can be calculated by the following formula :

$$P_{D(MAX)} = (125^\circ\text{C} - 25^\circ\text{C}) / (243.3^\circ\text{C/W}) = 0.41\text{W for SOT-23-3 package}$$

$$P_{D(MAX)} = (125^\circ\text{C} - 25^\circ\text{C}) / (167.7^\circ\text{C/W}) = 0.59\text{W for SOT-89-3 package}$$

For a fixed $T_{J(MAX)}$ of 125°C, the maximum power dissipation depends on the operating ambient temperature and the package's thermal resistance, θ_{JA} . The derating curve in Figure 1 shows the effect of rising ambient temperature on the maximum recommended power dissipation.

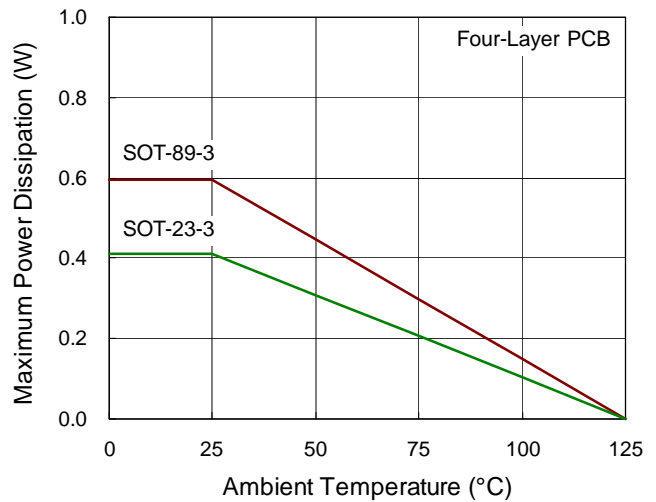
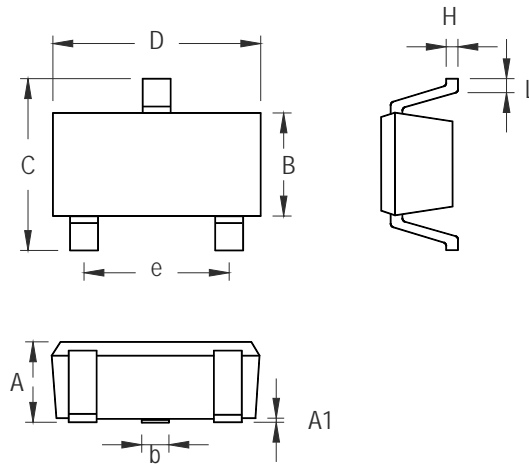


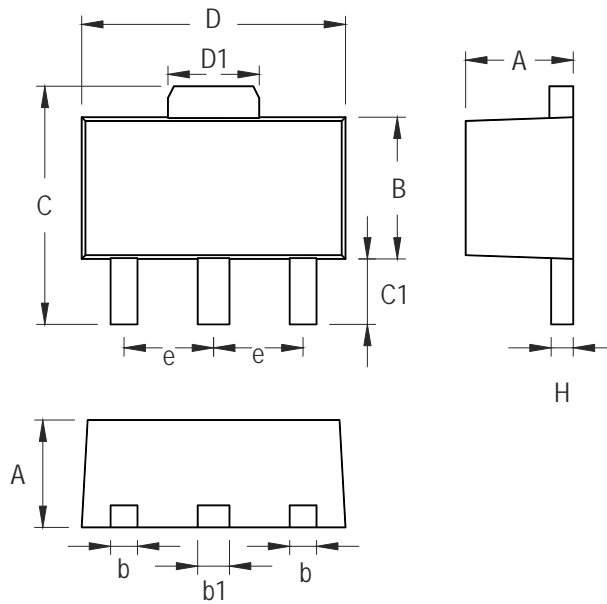
Figure 1. Derating Curve of Maximum Power Dissipation

Outline Dimension



Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min	Max	Min	Max
A	0.889	1.295	0.035	0.051
A1	0.000	0.152	0.000	0.006
B	1.397	1.803	0.055	0.071
b	0.356	0.508	0.014	0.020
C	2.591	2.997	0.102	0.118
D	2.692	3.099	0.106	0.122
e	1.803	2.007	0.071	0.079
H	0.080	0.254	0.003	0.010
L	0.300	0.610	0.012	0.024

SOT-23-3 Surface Mount Package



Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min	Max	Min	Max
A	1.397	1.600	0.055	0.063
b	0.356	0.483	0.014	0.019
B	2.388	2.591	0.094	0.102
b1	0.406	0.533	0.016	0.021
C	3.937	4.242	0.155	0.167
C1	0.787	1.194	0.031	0.047
D	4.394	4.597	0.173	0.181
D1	1.397	1.753	0.055	0.069
e	1.448	1.549	0.057	0.061
H	0.356	0.432	0.014	0.017

3-Lead SOT-89 Surface Mount Package

Richtek Technology Corporation

14F, No. 8, Tai Yuen 1st Street, Chupei City

Hsinchu, Taiwan, R.O.C.

Tel: (8863)5526789

Richtek products are sold by description only. Richtek reserves the right to change the circuitry and/or specifications without notice at any time. Customers should obtain the latest relevant information and data sheets before placing orders and should verify that such information is current and complete. Richtek cannot assume responsibility for use of any circuitry other than circuitry entirely embodied in a Richtek product. Information furnished by Richtek is believed to be accurate and reliable. However, no responsibility is assumed by Richtek or its subsidiaries for its use; nor for any infringements of patents or other rights of third parties which may result from its use. No license is granted by implication or otherwise under any patent or patent rights of Richtek or its subsidiaries.

单击下面可查看定价，库存，交付和生命周期等信息

[>>Richtek\(台湾立锜\)](#)